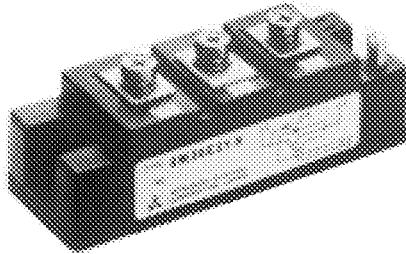


MITSUBISHI TRANSISTOR MODULES
QM30E2Y/E3Y-H

MEDIUM POWER SWITCHING USE
 INSULATED TYPE

QM30E2Y/E3Y-H



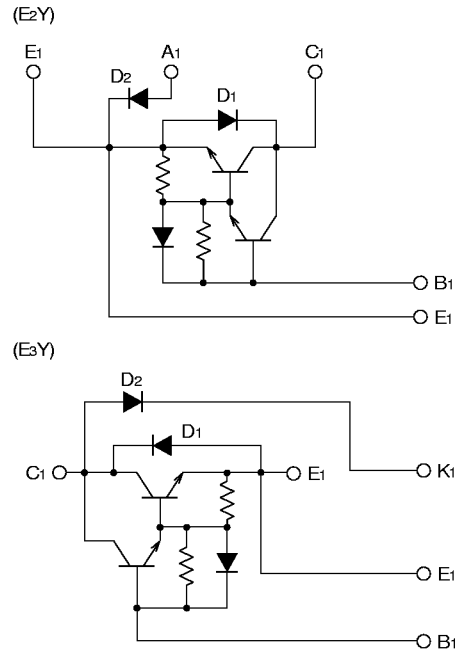
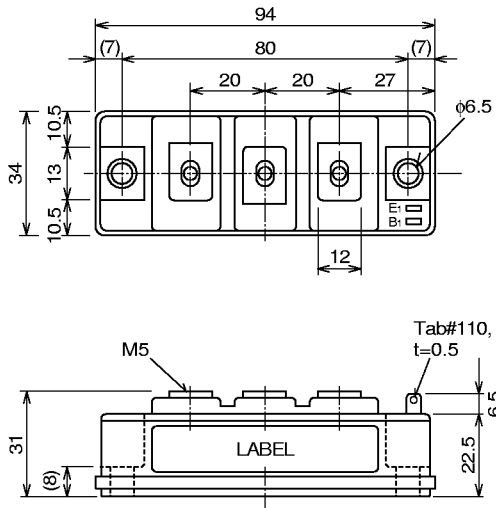
- **I_c** Collector current **30A**
- **V_{CEX}** Collector-emitter voltage **600V**
- **h_{FE}** DC current gain..... **75**
- **Insulated Type**
- **UL Recognized**
 Yellow Card No. E80276 (N)
 File No. E80271

APPLICATION

DC chopper, DC motor controllers, Inverters

OUTLINE DRAWING & CIRCUIT DIAGRAM

Dimensions in mm



QM30E2Y/E3Y-H

**MEDIUM POWER SWITCHING USE
INSULATED TYPE**

ABSOLUTE MAXIMUM RATINGS (Transistor part including D1, T_j=25°C)

Symbol	Parameter	Conditions	Ratings	Unit
V _{CEX(SUS)}	Collector-emitter voltage	I _c =1A, V _{EB} =2V	600	V
V _{CEX}	Collector-emitter voltage	V _{EB} =2V	600	V
V _{CB0}	Collector-base voltage	Emitter open	600	V
V _{EB0}	Emitter-base voltage	Collector open	7	V
I _c	Collector current	DC	30	A
-I _c	Collector reverse current	DC (forward diode current)	30	A
P _c	Collector dissipation	T _c =25°C	250	W
I _B	Base current	DC	1.8	A
-I _{CSM}	Surge collector reverse current (forward diode current)	Peak value of one cycle of 60Hz (half wave)	300	A

ABSOLUTE MAXIMUM RATINGS (Diode part (D2), T_j=25°C)

Symbol	Parameter	Conditions	Ratings	Unit
V _{RRM}	Repetitive peak reverse voltage		600	V
V _{RSM}	Non-repetitive peak reverse voltage		720	V
V _{R(DC)}	DC reverse voltage		480	V
I _{DC}	DC current	DC circuit, resistive, inductive load	30	A
I _{FSM}	Surge (non-repetitive) forward current	Peak value of one cycle of 60Hz (half wave)	600	A
I _{F1}	I _{F1} for fusing	Value for one cycle of surge current	1.5 × 10 ³	A ² s

ABSOLUTE MAXIMUM RATINGS (Common)

Symbol	Parameter	Conditions	Ratings	Unit
T _j	Junction temperature		-40~150	°C
T _{stg}	Storage temperature		-40~125	°C
V _{iso}	Isolation voltage	Charged part to case, AC for 1 minute	2500	V
—	Mounting torque	Main terminal screw M5	1.47~1.96	N·m
			15~20	kg·cm
		Mounting screw M6	1.96~2.94	N·m
			20~30	kg·cm
—	Weight	Typical value	210	g

ELECTRICAL CHARACTERISTICS (Transistor part including D1, T_j=25°C)

Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
I _{CEX}	Collector cutoff current	V _{CE} =600V, V _{EB} =2V	—	—	1.0	mA
I _{CB0}	Collector cutoff current	V _{CB} =600V, Emitter open	—	—	1.0	mA
I _{EB0}	Emitter cutoff current	V _{EB} =7V	—	—	200	mA
V _{CE(sat)}	Collector-emitter saturation voltage	I _c =30A, I _B =0.4A	—	—	2.0	V
V _{BE(sat)}	Base-emitter saturation voltage		—	—	2.5	V
-V _{CEO}	Collector-emitter reverse voltage	-I _c =30A (diode forward voltage)	—	—	1.85	V
h _{FE}	DC current gain	I _c =30A, V _{CE} =2V/5V	75/100	—	—	—
t _{on}	Switching time	V _{CC} =300V, I _c =30A, I _{B1} =-I _{B2} =0.6A	—	—	1.5	μs
t _s			—	—	12	μs
t _f			—	—	3.0	μs
R _{th(j-c)Q}	Thermal resistance (junction to case)	Transistor part	—	—	0.5	°C/W
R _{th(j-c)R}		Diode part	—	—	2.0	°C/W
R _{th(c-f)}	Contact thermal resistance (case to fin)	Conductive grease applied	—	—	0.15	°C/W

QM30E2Y/E3Y-H

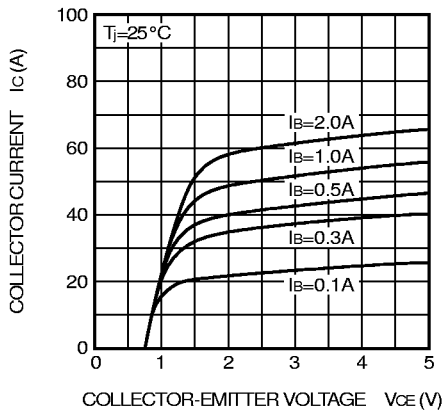
MEDIUM POWER SWITCHING USE
INSULATED TYPE

ELECTRICAL CHARACTERISTICS (Diode part (D2), $T_j=25^\circ\text{C}$)

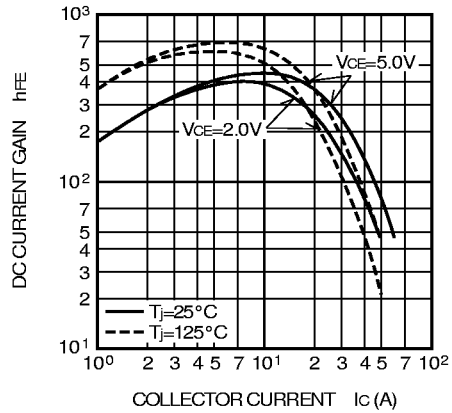
Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
I_{RRM}	Repetitive peak reverse current	$V_R=V_{RRM}, T_j=150^\circ\text{C}$	—	—	5.0	mA
V_{FM}	Forward voltage	$I_F=30\text{A}$	—	—	1.5	V
t_{rr}	Reverse recovery time	$I_F=30\text{A}, di/dt=-60\text{A}/\mu\text{s}, V_R=600\text{V}, T_j=150^\circ\text{C}$	—	—	0.9	μs
Q_{rr}	Reverse recovery charge		—	—	15	μC
$R_{th(j-c)}$	Thermal resistance	Junction to case	—	—	1.3	$^\circ\text{C}/\text{W}$
$R_{th(c-f)}$	Contact thermal resistance	Conductive grease applied (case to fin)	—	—	0.15	$^\circ\text{C}/\text{W}$

PERFORMANCE CURVES

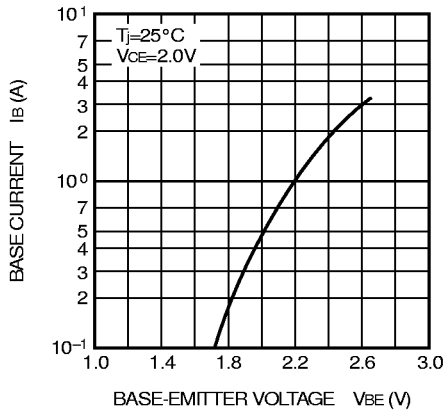
COMMON EMITTER OUTPUT CHARACTERISTICS (TYPICAL)



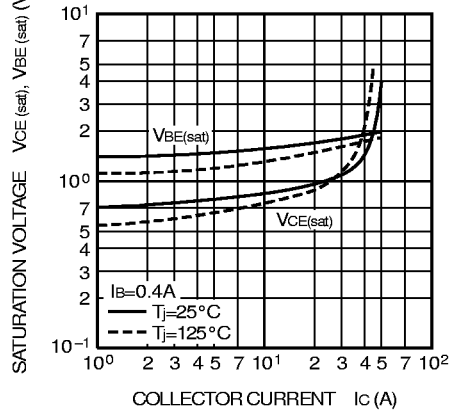
DC CURRENT GAIN VS. COLLECTOR CURRENT (TYPICAL)



COMMON EMITTER INPUT CHARACTERISTIC (TYPICAL)



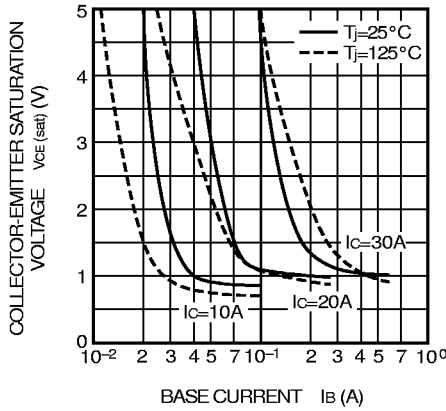
SATURATION VOLTAGE CHARACTERISTICS (TYPICAL)



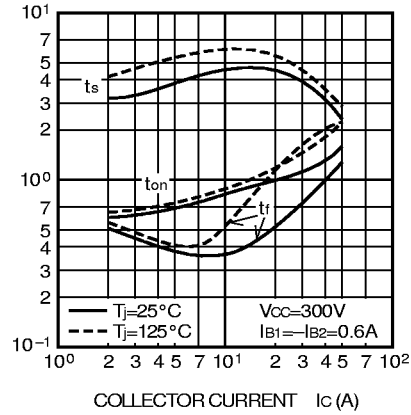
QM30E2Y/E3Y-H

MEDIUM POWER SWITCHING USE
INSULATED TYPE

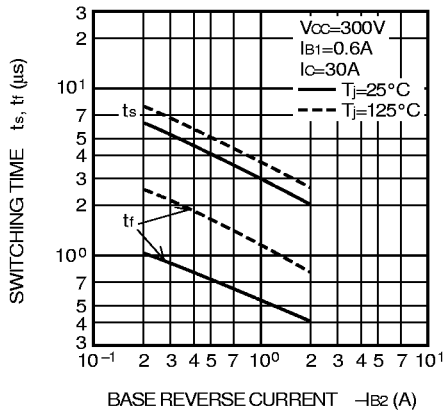
COLLECTOR-EMITTER SATURATION VOLTAGE (TYPICAL)



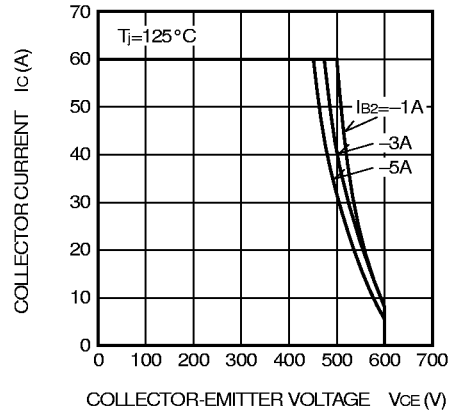
SWITCHING TIME VS. COLLECTOR CURRENT (TYPICAL)



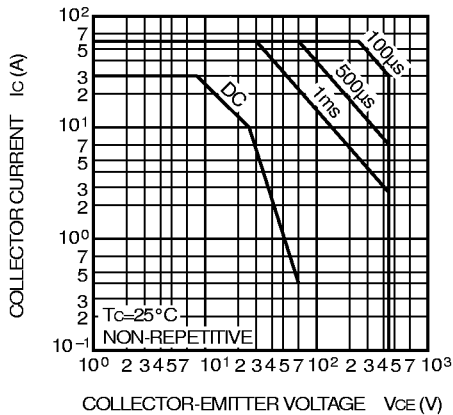
SWITCHING TIME VS. BASE CURRENT (TYPICAL)



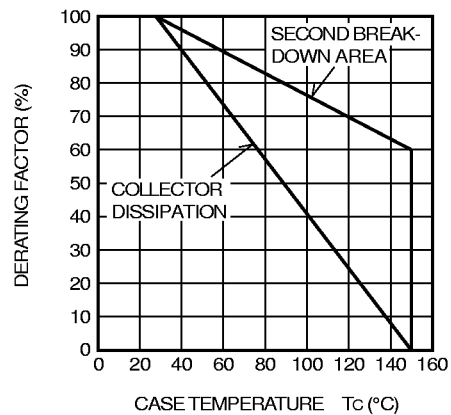
REVERSE BIAS SAFE OPERATING AREA



FORWARD BIAS SAFE OPERATING AREA

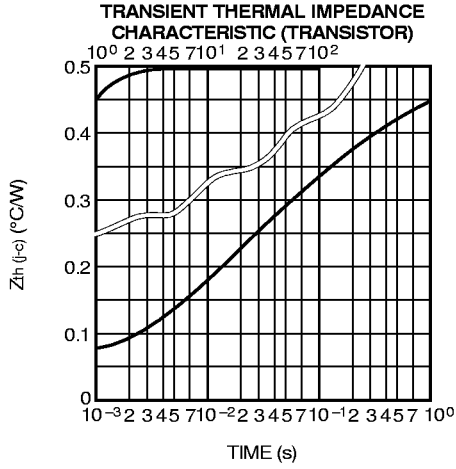


DERATING FACTOR OF F. B. S. O. A.

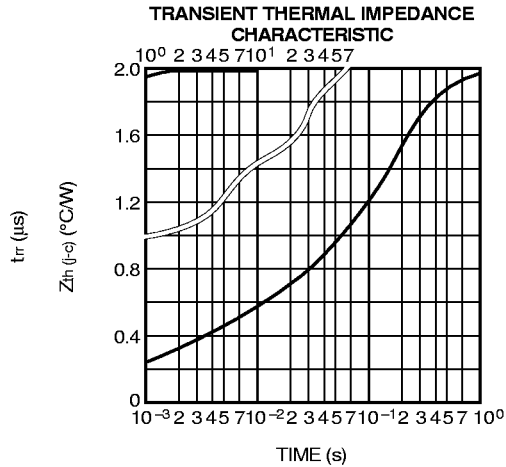
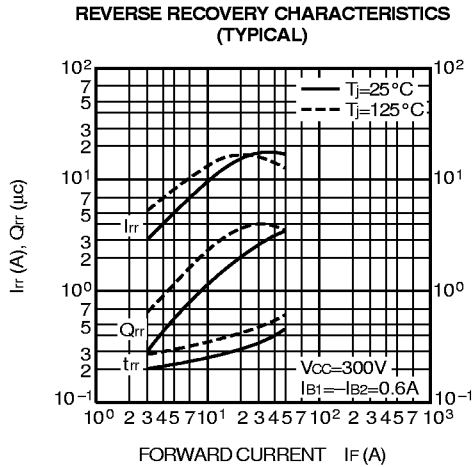
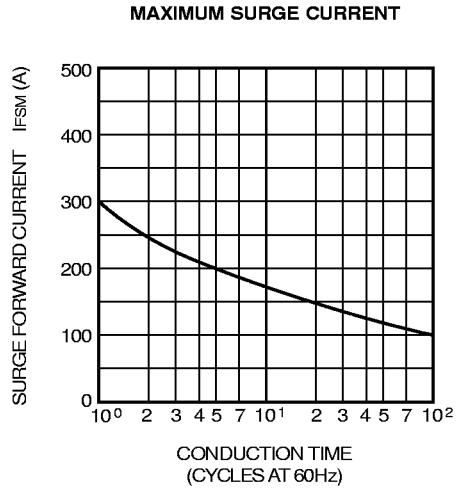
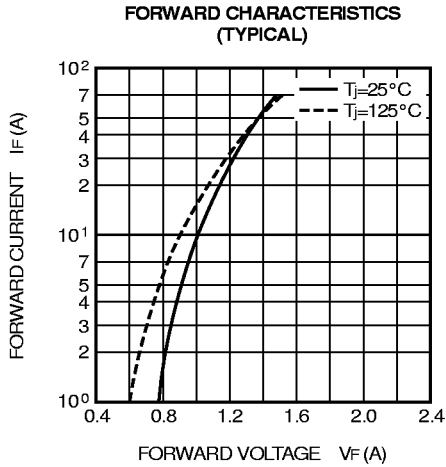


QM30E2Y/E3Y-H

MEDIUM POWER SWITCHING USE
INSULATED TYPE



PERFORMANCE CURVES (Diode part (D1))

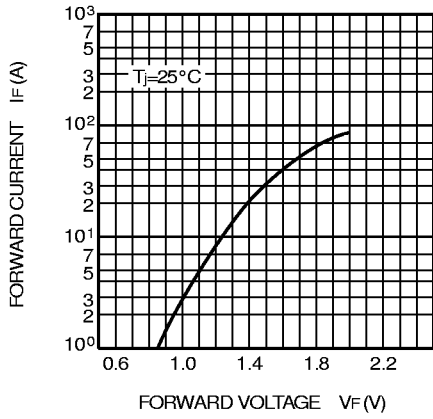


QM30E2Y/E3Y-H

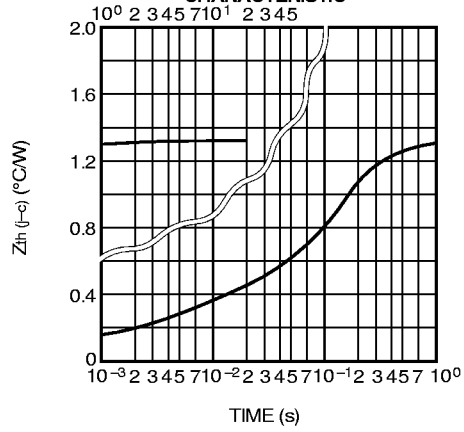
MEDIUM POWER SWITCHING USE
INSULATED TYPE

PERFORMANCE CURVES (Diode part (D2))

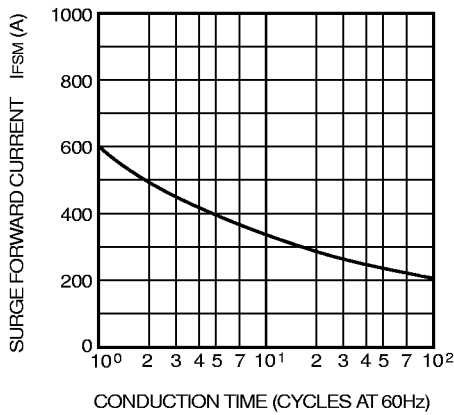
MAXIMUM FORWARD CHARACTERISTIC



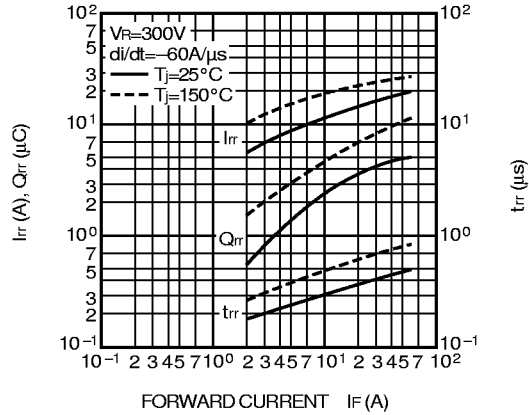
TRANSIENT THERMAL IMPEDANCE CHARACTERISTIC



MAXIMUM SURGE CURRENT



REVERSE RECOVERY CHARACTERISTICS (VS. I_F) (TYPICAL)



REVERSE RECOVERY CHARACTERISTICS (VS. di/dt) (TYPICAL)

